# **General Purpose Transistors**

# **NPN Silicon**

These transistors are designed for general purpose amplifier applications. They are housed in the SC-75/SOT-416 package which is designed for low power surface mount applications.

#### **Features**

• Pb-Free Packages are Available\*

## **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating	Symbol	Max	Unit
Collector–Emitter Voltage	V <sub>CEO</sub>	45	V
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	V
Collector Current – Continuous	I <sub>C</sub>	100	mAdc

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

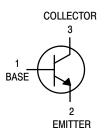
#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation,  FR-4 Board (Note 1)  T <sub>A</sub> = 25°C  Derated above 25°C	P <sub>D</sub>	200	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ heta JA}$	600	°C/W
Total Device Dissipation, FR-4 Board (Note 2) T <sub>A</sub> = 25°C Derated above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	400	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

- 1. FR-4 @ min pad.
- 2. FR-4 @ 1.0 × 1.0 in pad.



## http://onsemi.com





CASE 463 SC-75/SOT-41 6 STYLE 1

#### **MARKING DIAGRAM**



xx = Device Code M = Date Code

## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS		1		•		•
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA)	BC847 Series	V <sub>(BR)CEO</sub>	45	_	_	V
Collector – Emitter Breakdown Voltage $(I_C = 10 \mu A, V_{EB} = 0)$	BC847 Series	V <sub>(BR)CES</sub>	50	_	-	V
Collector – Base Breakdown Voltage ( $I_C = 10 \mu A$ )	BC847 Series	V <sub>(BR)CBO</sub>	50	_	-	V
Emitter – Base Breakdown Voltage ( $I_E = 1.0 \mu A$ )	BC847 Series	V <sub>(BR)EBO</sub>	6.0	_	-	V
Collector Cutoff Current (V <sub>CB</sub> = 30 V) (V <sub>C</sub>	<sub>CB</sub> = 30 V, T <sub>A</sub> = 150°C)	I <sub>CBO</sub>	-	- -	15 5.0	nA μA
ON CHARACTERISTICS				•	•	•
DC Current Gain ( $I_C = 10 \mu A$ , $V_{CE} = 5.0 V$ )	BC847A BC847B BC847C	h <sub>FE</sub>	1 1 1	90 150 270	- - -	_
$(I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$	BC847A BC847B BC847C		110 200 420	180 290 520	220 450 800	
Collector – Emitter Saturation Voltage ( $I_C$ = 10 mA, $I_B$ = 0.5 mA) ( $I_C$ = 100 mA, $I_B$ = 5.0 mA)		V <sub>CE(sat)</sub>	-	- -	0.25 0.6	V
Base – Emitter Saturation Voltage ( $I_C = 10$ mA, $I_B = 0.5$ mA) ( $I_C = 100$ mA, $I_B = 5.0$ mA)		V <sub>BE(sat)</sub>	-	0.7 0.9	- -	V
Base – Emitter Voltage ( $I_C$ = 2.0 mA, $V_{CE}$ = 5.0 V) ( $I_C$ = 10 mA, $V_{CE}$ = 5.0 V)		V <sub>BE(on)</sub>	580 -	660 -	700 770	mV
SMALL-SIGNAL CHARACTERISTICS						
Current – Gain – Bandwidth Product ( $I_C = 10$ mA, $V_{CE} = 5.0$ Vdc, $f = 100$ MHz)		f <sub>T</sub>	100	_	_	MHz
Output Capacitance (V <sub>CB</sub> = 10 V, f = 1.0 MHz)		C <sub>obo</sub>	_	-	4.5	pF
Noise Figure (I <sub>C</sub> = 0.2 mA, $V_{CE}$ = 5.0 Vdc, $R_S$ = 2.0 k $\Omega$ , f = 1.0 kHz, BW = 200 Hz)		NF	_	_	10	dB

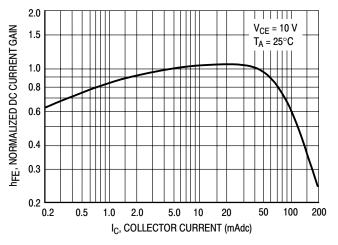


Figure 1. Normalized DC Current Gain

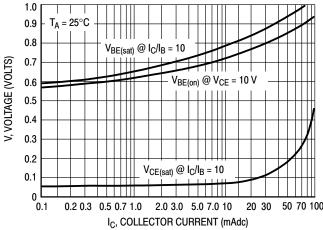


Figure 2. "Saturation" and "On" Voltages

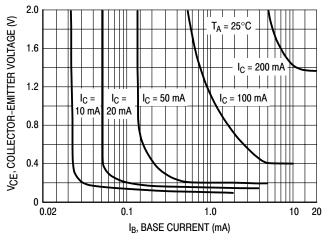


Figure 3. Collector Saturation Region

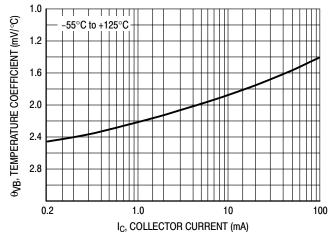


Figure 4. Base-Emitter Temperature Coefficient

# **BC847**

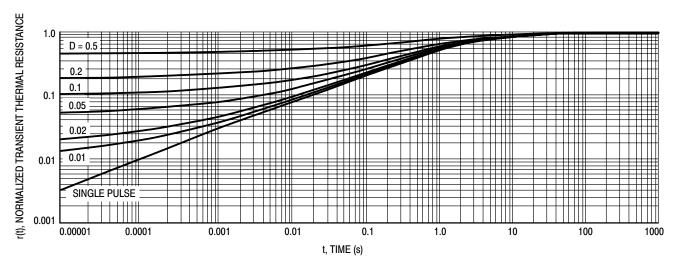


Figure 5. Normalized Thermal Response

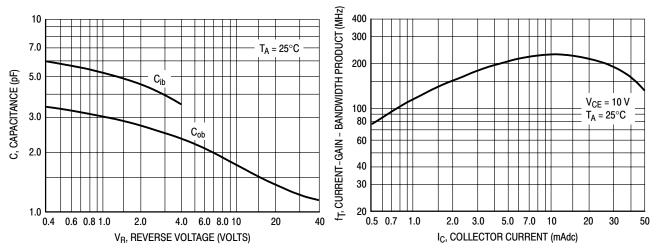


Figure 6. Capacitances Figure 7. Current-Gain - Bandwidth Product

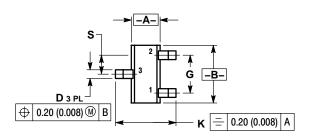
# **ORDERING INFORMATION**

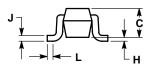
Device	Marking	Package	Shipping <sup>†</sup>	
BC847ATT1	1E	SC-75/SOT-416	3,000 / Tape & Reel	
BC847BTT1	1F	SC-75/SOT-416		
BC847BTT1G	1F	SC-75/SOT-416 (Pb-Free)	3,000 / Tape & Reel	
BC847CTT1	1G	SC-75/SOT-416		
BC847CTT1G	1G	SC-75/SOT-416 (Pb-Free)	3,000 / Tape & Reel	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **PACKAGE DIMENSIONS**

SC-75/SOT-416 CASE 463-01 ISSUE C





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	0.70	0.90	0.028	0.035	
В	1.40	1.80	0.055	0.071	
C	0.60	0.90	0.024	0.035	
D	0.15	0.30	0.006	0.012	
G	1.00 BSC		0.039 BSC		
Н		0.10		0.004	
J	0.10	0.25	0.004	0.010	
K	1.45	1.75	0.057	0.069	
L	0.10	0.20	0.004	0.008	
S	0.50	0.50 BSC 0.02		BSC	

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